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ELECTRONIC DEVICE

Abstract

An electronic device includes a substrate, a first bonding pad, a second bonding pad, a first electronic unit, a second electronic unit and a conductive wire. The first bonding pad is disposed on the substrate. The second bonding pad is disposed on the substrate. The first electronic unit includes a first electrode bonding on the first bonding pad. The second electronic unit includes a second electrode bonding on the second bonding pad. The conductive wire electrically connects the first electronic unit and the second electronic unit. A size of the first electronic unit is different from a size of the second electronic unit.

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Background/Summary

CROSS-REFERENCE TO RELATED APPLICATION [0001] This application is a continuation application of and claims the priority benefit of a prior U.S. application Ser. No. 18/169,187, filed on Feb. 14, 2023. The prior U.S. application Ser. No. 18/169,187 is a continuation application of and claims the priority benefit of a prior application Ser. No. 16/856,058, filed on Apr. 23, 2020. The entirety of each of the above-mentioned patent applications is hereby incorporated by reference herein and made a part of this specification.

BACKGROUND

Technical Field

[0002] The disclosure relates to an electronic device, and more particularly to an electronic device having an electrostatic discharge protective unit.

Description of Related Art

[0003] Electronic products have become indispensable in the modern society so the electronic devices need to continue to improve, such as increasing the production yield or reducing a damaging from the electrostatic discharge.

SUMMARY

[0004] The disclosure is directed to an electronic device, which may utilize an electrostatic discharge protective unit to protect the electronic device from damage by an electrostatic discharge.

[0005] According to an embodiment of the disclosure, an electronic device includes a substrate, a first bonding pad, a second bonding pad, a first electronic unit, a second electronic unit and a conductive wire. The first bonding pad is disposed on the substrate. The second bonding pad is disposed on the substrate. The first electronic unit includes a first electrode bonding on the first bonding pad. The second electronic unit includes a second electrode bonding on the second bonding pad. The conductive wire electrically connects the first electronic unit and the second electronic unit. A size of the first electronic unit is different from a size of the second electronic unit.

[0006] To make the aforementioned more comprehensible, several embodiments accompanied with drawings are described in detail as follows.

Description

BRIEF DESCRIPTION OF THE DRAWINGS

[0007] The accompanying drawings are included to provide a further understanding of the disclosure, and are incorporated in and constitute a part of the specification. The drawings illustrate exemplary embodiments of the disclosure and, together with the description, serve to explain the principles of the disclosure.

[0008] FIG. 1 is a schematic cross-sectional view of a pick-and-place tool and a carrier substrate when transferring a plurality of light emitting units according to an embodiment of the disclosure.

[0009] FIG. 2A is a schematic top view of a carrier substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0010] FIG. 2B is a schematic cross-sectional view of the carrier substrate of FIG. 2A along the section line A-A'.

[0011] FIG. 3A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0012] FIG. 3B is a schematic circuit diagram of the object substrate in FIG. 3A.

[0013] FIG. 4A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0014] FIG. 4B is a schematic top view of grounding the electrostatic discharge protective units of the object substrate in FIG. 4A.

[0015] FIG. 5A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0016] FIG. 5B is a schematic top view of grounding the electrostatic discharge protective units of the object substrate in FIG. 5A.

[0017] FIG. 6A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0018] FIG. 6B is a schematic top view of grounding the electrostatic discharge protective units of the object substrate in FIG. 6A.

[0019] FIG. 6C is a timing diagram of a data line voltage and a gate voltage of FIG. 6A.

[0020] FIG. 6D is another timing diagram of a data line voltage and a gate voltage of FIG. 6A.

[0021] FIG. 7 is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0022] FIG. 8 is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0023] FIG. 9A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure.

[0024] FIG. 9B is a schematic circuit diagram of the object substrate in FIG. 9A.

DESCRIPTION OF THE EMBODIMENTS

[0025] The disclosure can be understood by referring to the following detailed description in conjunction with the accompanying drawings. It should be noted that in order to make the reader easy to understand and for the sake of simplicity of the drawings, the multiple drawings in the disclosure only depict a part of the electronic device, and certain elements in the drawings are not drawn according to actual scale. In addition, the number and size of each element in the figure are only for illustration, and are not intended to limit the scope of the present disclosure.

[0026] In the following specification and claims, the words “containing” and “including” are open-ended words, and therefore they should be interpreted as meaning “including but not limited to”.

[0027] It will be understood that when an element or layer is referred to as being “(electrically) connected to” another element or layer, it can be directly (electrically) connected to the other element or layer, or intervening elements or layers may be presented. In contrast, when an element is referred to as being “directly (electrically) connected to” another element or layer, there are no intervening elements or layers presented. In contrast, when an element is referred to as being “disposed on” or “formed on” A element, it may be directly disposed on (or formed on) A element, or may be indirectly disposed on (or formed on) A element through other component. In contrast, when an element is referred to as being “disposed between” A element and B element, it may be directly disposed between A element and B element, or may be indirectly disposed between A element and B element through other component.

[0028] The terms “about”, “substantially”, “equal”, or “same” generally mean within 20% of a given value or range, or mean within 10%, 5%, 3%, 2%, 1%, or 0.5% of a given value or range. In addition, the phrase “in a range from a first value to a second value” indicates the range includes the first value, the second value, and other values in between.

[0029] It will be understood that when “A element is electrically connected to the thin film transistor” or “A element is electrically connected to the B element through the thin film transistor”, which may be in a condition that the thin film transistor is turned on.

[0030] The electronic device of the disclosure may include, but is not limited to, a display device, an antenna device, a lighting device, a sensing device, a touch device, a curved device, or a free shape device, a bendable device, a flexible device or a tiled device. The electronic device may include LED (light-emitting diode) display, micro-LED display, mini-LED display, a quantum dots LEDs (QLEDs or QD-LEDs) display, fluorescence materials, phosphor materials, other suitable displays, or a combination thereof, but not limited thereto.

[0031] Although the terms first, second, third etc. can be used to describe various constituent elements, the constituent elements are not limited by the term. The term is only used to distinguish a single constituent element from other constituent elements in the specification. The same terms may not be used in the claims, but may be replaced by first, second, third, etc. in the order of element declarations in the claims. Therefore, in the following specification, a first constituent element may be a second constituent element in the claims.

[0032] In some embodiments of the present disclosure, unless specifically defined otherwise, the terms related to joining and connection, such as “connected” and “interconnected”, may refer to two structures being in direct contact, or may refer to two structures not being in direct contact and other structures are provided between the two structures. Moreover, the terms about joining and connecting may include a case where two structures are movable or two structures are fixed. In addition, the term “coupled” includes any direct and indirect electrical connection means.

[0033] It should be noted that the technical features in different embodiments described in the following can be replaced, recombined, or mixed with one another to constitute another embodiment without departing from the spirit of the present disclosure.

[0034] Reference will now be made in detail to the exemplary embodiments of the disclosure, examples of which are illustrated in the accompanying drawings. Whenever possible, the same reference numerals are used to represent the same or similar parts in the accompanying drawings and description.

[0035] In the present embodiment, a method for manufacturing an electronic device includes transferring a plurality of light emitting units from a carrier substrate to an object substrate under protection of at least one electrostatic discharge protective unit. In detail, transferring the plurality of light emitting units from the carrier substrate to the object substrate may include the following steps: 1) picking the plurality of light emitting units from the carrier substrate by a pick-and-place tool, and then 2) placing the plurality of light emitting units onto the object substrate.

[0036] In addition, in the step of picking the plurality of light emitting units from the carrier substrate by the pick-and-place tool, when the pick-and-place tool contacts the plurality of light emitting units on the carrier substrate, electrostatic discharge may be generated to damage the plurality of light emitting units. In the step of placing the plurality of light emitting units onto the object substrate, when the plurality of light emitting units located on the pick-and-place tool contact to the object substrate, electrostatic discharge also may be generated to damage the plurality of light emitting units or the object substrate.

[0037] In addition, the steps (the steps 1 and the step 2) may be both performed under a protection by at least one electrostatic discharge protective unit (such as the following first electrostatic discharge protective unit ESDP1, second electrostatic discharge protective unit ESDP2, and/or third electrostatic discharge protective unit ESDP3).

[0038] Therefore, in some embodiments, an electrostatic discharge protective unit may be provided in the pick-and-place tool to reduce the electrostatic discharge generated in the above two steps from damaging the plurality of light emitting units or the object substrate. In some embodiments, electrostatic discharge protective units may be provided in the carrier substrate and/or the object substrate to reduce the electrostatic discharge generated in the above two steps from damaging the plurality of light emitting units or the object substrate. In some embodiments, electrostatic discharge protective units may be provided in the pick-and-place tool, the carrier substrate and/or the object substrate to reduce the electrostatic discharge generated in the above two steps from

damaging the plurality of light emitting units or the object substrate.

[0039] In the following, several embodiments will be listed in conjunction with the drawings to explain in detail how to configure the electrostatic discharge protective units in the pick-and-place tool, the carrier substrate and/or the object substrate.

[0040] FIG. 1 is a schematic cross-sectional view of a pick-and-place tool and a carrier substrate when transferring a plurality of light emitting units according to an embodiment of the disclosure.

[0041] Referring to FIG. 1, in the present embodiment, a pick-and-place tool **100** includes a body **110**, some grasping heads **120**, **121**, **122**, **123** and a conductive metal wire **130**. The conductive metal wire **130** includes a body portion **131** and a plurality of extension portions **132**, **133**, **134**, **135**. The body portion **131** is disposed in the body **110** of the pick-and-place tool **100**, and the plurality of extension portions **132**, **133**, **134**, **135** of the conductive metal wire **130** are respectively extended from the body portion **131** to different grasping heads **120**, **121**, **122**, **123**, and the extension portions **132**, **133**, **134**, **135** are in different patterns, but is not limited thereto. For example, the extension portion **132** extended into the grasping head **120** is a linear pattern. The extension portion **133** extended into the gripping head **121** is a loop pattern, the extension portion **134** extended to a surface **122a** of the grasping head **122** facing the plurality of light emitting units **300** is a linear pattern, the extension portion **135** extended to a surface **123a** of the grasping head **123** facing the plurality of light emitting units **300** is a loop pattern, but is not limited thereto. In other embodiment, the pattern of the plurality of extension portions **132**, **133**, **134**, **135** may change according to demand. In some embodiments, a material of the grasping heads **120**, **121**, **122**, **123** may include polydioxanone (PDS)-based polymer material, viscous material, elastic material, polydimethylsiloxane (PDMS) or a combination of the above, but is not limited thereto. In some embodiments (not shown), the extension portions of the conductive metal wire disposed in different gripping heads may also have the same pattern.

[0042] Then, the body portion **131** of the conductive metal wire **130** is connected to a ground GND or low potential voltage (not shown) by a wire, as shown by a dotted line D1. Therefore, during the step of transferring the plurality of light emitting units **300** from a carrier substrate **200** to the object substrate (not shown), an electrostatic discharge generated when the grasping heads **120**, **121**, **122**, **123** of the pick-and-place tool **100** contact the plurality of light emitting units **300** on the carrier substrate **200** can be reduced or removed by grounding the conductive metal wire **130**. As a result, the generated electrostatic discharge can be reduced or removed to reduce a damaging of the plurality of light emitting units **300**. Therefore, in the present embodiment, the conductive metal wire **130** located in the pick-and-place tool **100** can be regarded as a first electrostatic discharge protective unit ESDP1. In other words, the first electrostatic discharge protective unit ESDP1 is located in the pick-and-place tool **100**. In other embodiment, the first electrostatic discharge protective unit ESDP1 may include the conductive metal wires **130** and/or a switching element.

[0043] In the present embodiment, the carrier substrate **200** includes a substrate **210**, a first conductive metal wire **220**. The substrate **210** includes a plurality of recesses **211**, a first surface **212**, and a second surface **213** opposite to the first surface **212**. The plurality of recesses **211** expose the third surface **214** of the substrate **210**. The first conductive metal wire **220** is disposed on the first surface **212** of the substrate **210** and the plurality of recesses **211**. In some embodiments, air can located between the recesses **211** and the first conductive metal wire **220**. The plurality of light emitting units **300** are disposed on the first conductive metal wire **220**, and the plurality of light emitting units **300** respectively overlaps the recesses **211**, but it is limited thereto. N-type electrode (not shown) of the light emitting units **300** are in contact with and electrically connected to the first conductive metal wire **220**, and P-type electrode (not shown) of the light emitting units **300** are in contact with and electrically connected to a second conductive metal wire (not shown). The second conductive metal wire is disposed on the first surface **212** of the substrate **210**.

[0044] Before the step of transferring the plurality of light emitting units **300** from the carrier

substrate **200** to the object substrate (not shown), an testing may be performed on the plurality of light emitting units **300** by respectively applying different signals to the first conductive metal wire **220** and the second conductive metal (not shown) to ensure the normal operation of the plurality of light emitting units **300**.

[0045] Then, after performing the testing, the conductive metal wire **220** can be connected to the ground GND (as shown by the dotted line D2), and the plurality of light emitting units can be transferred. During the step of transferring the plurality of light emitting units **300** from the carrier substrate **200** to the object substrate (not shown), the electrostatic discharge generated when the grasping heads **120, 121, 122, 123** of the pick-and-place tool **100** contact the plurality of light emitting units **300** on the carrier substrate **200** can be reduced or removed by grounding the conductive metal wire **220** located in the carrier substrate **200**, it can reduce damaging of the plurality of light emitting units **300**. Therefore, in the present embodiment, the conductive metal wire **220** provided in the carrier substrate **200** can be regarded as a second electrostatic discharge protective unit ESDP2, but is not limited thereto. In other words, the second electrostatic discharge protective unit ESDP2 is located in the carrier substrate **200**, and the second electrostatic discharge protective unit ESDP2 is the conductive metal wire **220**.

[0046] FIG. 2A is a schematic top view of a carrier substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. FIG. 2B is a schematic cross-sectional view of the carrier substrate of FIG. 2A along the section line A-A'. Please refer to FIG. 1 and FIGS. 2A-2B, the carrier substrate **200a** in the present embodiment is substantially similar to the carrier substrate **200** in FIG. 1. The carrier substrate **200a** is different from the carrier substrate **200** mainly in that: the carrier substrate **200a** further includes a fixing layer **230** disposed on the plurality of conductive metal wires **220a** and the plurality of light emitting units **300**, and the plurality of conductive metal wires **220a** do not contact with the plurality of light emitting units **300**. The electrostatic charges generated when the grasping heads **120, 121, 122, 123** of the pick-and-place tool **100** contact the plurality of light emitting units **300** on the carrier substrate **200a** can be transfer by the fixing layer **230** to the conductive metal wires **220a**, the electrostatic charges may be removed by grounding the conductive metal wires **220a** (which be regarded as a second electrostatic discharge protective unit ESDP2 located in the carrier substrate **200a**). In other word, the conductive metal wire **220a** is connected to a ground GND (or low potential, not shown), as shown by the dashed line D3. In some embodiments, a material of the fixing layer **230** may include silicon nitride, silicon oxide, other suitable materials or combination of the above, but is not limited thereto.

[0047] The plurality of light emitting units **300** overlap with the recesses **211**, the fixing layer **230** is disposed on the first surface **212** of the substrate **210** and/or covers at least portion of the plurality of light emitting units **300**, a portion of the plurality of recesses **211**, and a portion of the conductive metal wires **220a**.

[0048] Therefore, during the step of transferring the plurality of light emitting units **300** from a carrier substrate **200a** to the object substrate (not shown), an electrostatic discharge generated when the grasping heads of the pick-and-place tool contact the plurality of light emitting units **300** on the carrier substrate **200a** can be reduced or removed by grounding the conductive metal wires **220a**. As a result, the generated electrostatic discharge can be removed to reduce damaging of the plurality of light emitting units **300**. Therefore, in some embodiments, the conductive metal wires **220a** provided in the carrier substrate **200a** can be regarded as a second electrostatic discharge protective unit ESDP2. In other words, the second electrostatic discharge protective unit ESDP2 is located in the carrier substrate **200a** and the second electrostatic discharge protective unit ESDP2. In some embodiments (not shown), a shape of the recesses **211** is not limited rectangles, the recesses **211** may include polygons shape, curved shape or other suitable shapes.

[0049] FIG. 3A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. FIG. 3B is a

schematic circuit diagram of the object substrate in FIG. 3A. Referring to FIG. 3A and FIG. 3B, in the present embodiment, an object substrate **400** includes a substrate **410**, a first thin film transistor **420** (such as a switching transistor), a second thin film transistor **430** (such as a driving transistor), a first switching element **440**, a plurality of bonding pads (such as a P-type bonding pad **450** and an N-type bonding pad **451**) and a patterned shading layer **460**. The substrate **410** may be a flexible substrate, a rigid substrate or a combination thereof. For example, a material of the substrate **410** may include metal, plastic, glass, quartz, sapphire, ceramic, polycarbonate (PC), polyimide (PI), polyethylene terephthalate (PET), glass fiber, other suitable substrate materials or a combination of the above, but is not limited thereto.

[0050] The patterned shading layer **460** is disposed on the substrate **410**. The first thin film transistor **420**, the second thin film transistor **430** and the first switching element **440** are respectively disposed on the patterned shading layer **460**. The second thin film transistor **430** is located between the first thin film transistor **420** and the first switching element **440**, and the second thin film transistor **430** is electrically connected between the first thin film transistor **420** and the first switching element **440**. The projection of the patterned shading layer **460** on the substrate **410** overlaps the projection of a channel region SE1 of the first thin film transistor **420**, a channel region SE2 of the second thin film transistor **430** and a channel region SE3 of the first switching element **440** on the substrate **410**, respectively. The channel region SE1, the channel region SE2 and/or the channel region SE3 formed of the same semiconductor layer or different semiconductor layers.

[0051] In addition, the first thin film transistor **420** (such as a drain of the first thin film transistor **420**) is electrically connected to the second thin film transistor **430** (such as a gate of the second thin film transistor **430**) through a wire of other cross-section (as shown by the dashed line L1). The first switching element **440** includes a gate **441**, a source region **443**, a drain region **444** and the channel region SE3, a portion of a gate insulating layer **442** is disposed between the channel region SE3 and the gate **441**, but is not limited thereto. In some embodiments, the gate **441** of the first switching element **440** is electrically connected to the source region **443** of the first switching element **440**, but is not limited thereto. In some embodiments, a drain region **431** of the second thin film transistor **430** is electrically connected to the gate **441** of the first switching element **440** and the P-type bonding pad **450**. In the present embodiment, a N-type bonding pad **451** may be electrically connected to the drain region **444** of the first switching element **440** through a wire of other cross-section (as shown by the dashed line L2), but is not limited thereto. In other embodiments, the N-type bonding pad **451** may not be electrically connected to the first switching element **440** (such as a drain region **444** of the first switching element **440**), and the N-type bonding pad **451** may be electrically connected to the ground (not shown) or low potential (not shown). In the present embodiment, the first switching element **440** disposed in a pixel region of the object substrate **400** is connected to a ground GND (or low potential (not shown)) through the drain region **444** of the first switching element **440**, as shown by a dotted line D4. The pixel region can be defined by the scan lines and the data lines, the scan lines **470** (not shown in the FIG. 3A, but can refer the FIG. 3B) and the data lines **471** (not shown in the FIG. 3A, but can refer the FIG. 3B) are interleaved to form multiple pixel region.

[0052] Therefore, during the step of transferring the plurality of light emitting units **300** from a carrier substrate (not shown) to the object substrate **400**, and the plurality of light emitting units **300** may be picked by the pick-and-place tool (not shown), an electrostatic discharge generated when a P-type electrode **450-1** of the light emitting unit **300** contact to the P-type bonding pad **450** of the object substrate **400**, and/or a N-type electrode **451-1** of the light emitting unit **300** contact to the N-type bonding pad **451** of the object substrate **400**, the electrostatic discharge can be reduced or removed by grounding the bonding pad of the object substrate **400** (such as the N-type bonding pad **451**), and the generated electrostatic discharge can be reduced or removed to reduce damaging the plurality of light emitting units **300** and/or the object substrate **400**. In the present embodiment,

the switches (such as the first switching element **440**) located in the object substrate **400** can be regarded as a third electrostatic discharge protective unit ESDP3. In other words, the at least one third electrostatic discharge protective unit ESDP3 is located in the object substrate **400**. In some embodiments, the at least one third electrostatic discharge protective unit ESDP3 located in the object substrate **400** is electrically connected to the plurality of bonding pads (such as P-type bonding pads **450** of the object substrate **400**). In some embodiments, the at least one third electrostatic discharge protective unit ESDP3 located in the object substrate **400** comprises a plurality of switches (such as the first switching element **440**) for grounding the bonding pads (such as P-type bonding pads **450**) during the step of transferring the plurality of light emitting units **300** from the carrier substrate **200** (or **200a**) to the object substrate **400**.

[0053] In the present embodiment, the object substrate **400** may further include scan lines **470**, data lines **471**, power supply lines **472** (such as VDD), capacitance **473**, common voltage wires (not shown) and/or signal reference wires (not shown, such as VSS), but is not limited thereto.

[0054] FIG. 4A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. FIG. 4B is a schematic top view of grounding the electrostatic discharge protective units of the object substrate in FIG. 4A. Please referring to FIG. 3A and FIG. 4A, an object substrate **400a** is substantially similar to the object substrate **400** in FIG. 3A. The object substrate **400a** is different from the object substrate **400** mainly in that: the object substrate **400a** further includes a second switching element **440'**, and the second switching element **440'** may be electrically connected to a first switching element **440a**. In some embodiments, the second switching element **440'** (the switch in claim) includes a gate **441'**, a source region **443'**, a drain region **444'** and a channel region SE3'. The gate **441'** of the second switching element **440'** is electrically connected to the source region **443'** of the second switching element **440'**. In addition, in the present embodiment, the drain region **444'** of the second switching element **440'** can contact and/or be electrically connected to the drain region **444** of the first switching element **440a**, a configuration structure of the first switching element **440a** and the second switching element **440'** can be regarded as a back-to-back diode. In other word, the at least one third electrostatic discharge protective unit ESDP3 located in the object substrate **400a** comprises back-to-back diode.

[0055] In some embodiments, the second switching element **440'** disposed in a pixel region of the object substrate **400a** is connected to a ground GND (or low potential, not shown) through the source region **443'** of the second switching element **440'**, as shown by a dotted line D5. In other words, the P-type bonding pad **450** can be electrically connected to the ground GND (or low potential, not shown) through the first switching element **440a** and the second switching element **440'**. In some embodiments, N-type bonding pad **451a** may be electrically connected to a ground GND (as shown by the dashed line D6), but is not limited thereto.

[0056] Therefore, in the present embodiment, the configuration structure of the first switching element **440a** and the second switching element **440'** (back-to-back diode) provided in the object substrate **400a** can be regarded as a third electrostatic discharge protective unit ESDP3. In other words, the third electrostatic discharge protective unit ESDP3 is the configuration structure of the first switching element **440a** and the second switching element **440'**. The third electrostatic discharge protective unit ESDP3 is located in the object substrate **400a**, and the third electrostatic discharge protective unit ESDP3 is electrically connected to the bonding pad of the object substrate **400a** (such as the P-type bonding pad **450**).

[0057] Referring again to FIG. 4B, the object substrate **400a** has a plurality of sub-pixel regions **401a** arranged on the substrate **410** in an array substrate (schematically shown as 9 sub-pixel regions in FIG. 4B, but is not limited thereto). The P-type bonding pad **450** in the sub-pixel regions **401a** of a first column C1 is connected to the ground line GND1 through the corresponding first switching element **440a** and/or the corresponding second switching element **440'**, but is not limited thereto. In addition, the P-type pad **450** in the sub-pixel regions **401a** of a second column C2 is

connected to the ground line GND2 through the corresponding first switching element **440a** and the corresponding second switching element **440'**. The P-type pad **450** in the sub-pixel regions **401a** of a third column C3 is connected to the ground line GND3 through the corresponding first switching element **440a** and the corresponding second switching element **440'**. In some embodiments, the ground line GND1, the ground line GND2 and/or the ground line GND3 may be electrical connect each other, but is not limited thereto.

[0058] FIG. 5A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. FIG. 5B is a schematic top view of grounding the electrostatic discharge protective units of the object substrate in FIG. 5A. Please referring to FIGS. 4A-4B and FIGS. 5A-5B, an object substrate **400b** is substantially similar to the object substrate **400a** in FIGS. 4A-4B. The object substrate **400b** is different from the object substrate **400a** mainly in that: a N-type bonding pad **451b** of the object substrate **400b** is electrically connected to the second switching element **440b**. Specifically, as shown in FIG. 5A, in the present embodiment, the N-type bonding pad **451b** of the object substrate **400b** is electrically connected to a source region **443'** of the second switching element **440b** through a wire of another cross section (as shown by a dotted line L3).

[0059] Referring to FIG. 5B, in the present embodiment, the object substrate **400b** has a plurality of sub-pixel regions **401b** arranged on the substrate **410** in an array (schematically shown as 9 sub-pixel regions in FIG. 5B, but is not limited thereto). The P-type bonding pad **450** in the sub-pixel regions **401b** of a first row R1 are connected to the ground line GND4. The N-type bonding pad **451b** and the P-type bonding pad **450** in the sub-pixel regions **401b** are electrical connected through the corresponding first switching element **440a** and the corresponding second switching element **440b**, and the P-type pad **450** and the N-type bonding pad **451b** in the sub-pixel regions **401a** of a first row R1 are connected to the ground line GND4. In addition, the P-type pad **450** and the N-type bonding pad **451b** in the sub-pixel regions **401a** of a second row R2 are connected to the ground line GND5 through the corresponding first switching element **440a** and the corresponding second switching element **440b**. The P-type pad **450** and the N-type bonding pad **451b** in the sub-pixel regions **401a** of a second row R3 are connected to the ground line GND6 through the corresponding first switching element **440a** and the corresponding second switching element **440b**.

[0060] FIG. 6A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. FIG. 6B is a schematic top view of grounding the electrostatic discharge protective units of the object substrate in FIG. 6A. Please referring to FIG. 3A and FIG. 6A, an object substrate **400c** in the present embodiment is substantially similar to the object substrate **400** in FIG. 3A. The object substrate **400c** is different from the object substrate **400** mainly in that: the object substrate **400c** does not include a first switching element.

[0061] Specifically, referring to FIG. 6A and FIG. 6B in the present embodiment, a second thin film transistor **430c** disposed in a pixel region **401c** of the object substrate **400c** is connected to a signal line **472'** through a source **432** of the second thin film transistor **430c**, as shown by a dotted line D7. It should be noted that, the signal line **472'** transfers a low potential or ground potential (GND) under a protection by at least one electrostatic discharge protective unit, and how to transfer the potentials through the signal line **472'** in different states can be referred to FIG. 6C~6D. In other words, a P-type bonding pad **450** may be electrically connected to the low potential or the ground GND through the second thin film transistor **430c**, but is not limited thereto. It should be noted that, the signal line **472'** transfers a high potential (such as VDD) under driving the pixel. It should be noted that, the potentials (the high potential, the low potential or ground potential) transferred by the signal line **472'** may be switched through IC chip (not shown) or controller (not shown).

[0062] Referring to FIG. 6B, in the present embodiment, the object substrate **400c** has a plurality of sub-pixel regions **401c** arranged in an array (schematically shown as 9 sub-pixel regions in FIG.

6B, but is not limited thereto). The plurality of sub-pixel regions **401c** are defined by staggering scan lines **470** and data lines **471** with each other. The P-type bonding pad **450** in the sub-pixel regions **401c** of the column C1 (column C2 or column C3) are connected to the signal line **472'** through the corresponding second thin film transistor **430c**. The signal lines **472'** transfer a low potential or ground potential (GND) under a protection by at least one electrostatic discharge protective unit.

[0063] Therefore, in the present embodiment, the second thin film transistor **430c** of the object substrate **400c** can be regarded as a third electrostatic discharge protective unit ESDP3. The third electrostatic discharge protective unit ESDP3 is located in the object substrate **400c** and is electrically connected to the P-type bonding pad **450**. In other embodiments, the P-type bonding pad **450** and N-type bonding pad **451** are replaced with each other.

[0064] Next, a design of a data line voltage and a gate voltage during the step of placing the plurality of light-emitting units **300** onto the object substrate **400c** will be exemplified. FIG. 6C is a timing diagram of a data line voltage and a gate voltage of FIG. 6A. FIG. 6D is another timing diagram of a data line voltage and a gate voltage of FIG. 6A.

[0065] Referring to FIG. 6C, in the present embodiment, during the step of placing the plurality of light emitting units **300** onto the object substrate **400c**, the interaction relationship between the pick-and-place tool, the plurality of light emitting units **300**, and the object substrate **400c** can be divided into three states. State A: the plurality of light emitting units **300** are located on the pick-and-place tool. In other word, the plurality of light emitting units **300** are picked up by the pick-and-place tool. State B: the plurality of light emitting units **300** located on the pick-and-place tool contact to the P-type bonding pad **450** and the N-type bonding pad **451** of the object substrate **400c**. State C: the plurality of light emitting units **300** detached from the pick-and-place tool are bonded to the P-type bonding pad **450** and the N-type bonding pad **451** of the object substrate **400c**.

[0066] In the present embodiment, the signal line **472'** voltage may be 0V (ground potential) or a low potential in the state A to state C. The gate voltage (such as scan line **470** voltage) may be 0V or low potential in the beginning of the state A. However, before preparing to enter the state B, the gate voltage may be a high potential, and the gate voltage (high potential) may be continued to be provided until entering into the state C, the gate voltage can be switched or restored to 0V or low potential.

[0067] Referring to FIG. 6D, in some embodiment, the design of the signal line **472'** voltage and the gate voltage may be different from FIG. 6C mainly in that: before preparing to enter the state B, the gate voltage may be a high potential. However, after entering into state B, the gate voltage may be switched or restored to 0V or low potential in part of time of the state B, and then the gate voltage may be switched to the high potential again in part of time of the state B. Then, before preparing to enter the state C, the gate voltage may be continued a high potential until entering into the state C.

[0068] FIG. 7 is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. Please referring to FIG. 3A and FIG. 7, an object substrate **400d** is substantially similar to the object substrate **400** in FIG. 3A. The object substrate **400d** is different from the object substrate **400** mainly in that: a first switching element **440d** of the object substrate **400d** may be electrically connected to a second thin film transistor **430** through the light emitting unit **300**, the first switching element **440d** may be electrically connected to the N-type bonding pad **451d**, the P-type bonding pad **450** may be electrically connected to the second thin film transistor **430**, and the first switching element **440d** and a second thin film transistor **430** are respectively disposed at two opposite sides of the substrate **410**.

[0069] The first switching element **440d** may be disposed in a non-pixel region of the object substrate **400**, but is not limited thereto. In other embodiments, in a normal direction of the substrate **410**, the first switching element **440d** may overlap with the light emitting unit **300**, but is

not limited thereto.

[0070] Specifically, in the present embodiment, the substrate **410** includes an upper surface **410a** and a bottom surface **410b** opposite to the upper surface **410a**. A first thin film transistor **420**, the second thin film transistor **430** and a light emitting unit **300** are disposed on the upper surface **410a** of the substrate **410**, and the first switching element **440d** and a chip **500** are disposed on the bottom surface **410b** of the substrate **410**. In some embodiments, the substrate **410** includes a side surface **410c** connecting with the upper surface **410a** and bottom **410b**, a conductive wire **480d** is disposed on the upper surface **410a** and extends along a side surface **410c** to the bottom surface **410b**. The conductive wire **480d** is electrically connected to the N-type bonding pad **451d**, the first switching element **440d** and the chip **500**. Specifically, the N-type bonding pad **451d** may be electrically connected to a gate **441d** of the first switching element **440d** through the conductive wire **480d**, and the gate **441d** of the first switching element **440d** may be electrically connected to a source region **443d** of the first switching element **440d**. The chip **500** may be electrically connected to the gate **441d** of the first switching element **440d** through the conductive wire **480d**.

[0071] In the present embodiment, the first switching element **440d** is connected to a ground GND (or low potential, not shown) through a drain region **444d** of the first switching element **440d**, as shown by a dotted line D8. In other words, the N-type bonding pad **451d** can be electrically connected to the ground GND (or low potential, not shown) through the conductive wire **480d** and the first switching element **440d**, but is not limited thereto.

[0072] Therefore, in the present embodiment, the first switching element **440d** provided or located in the object substrate **400d** can be regarded as a third electrostatic discharge protective unit ESDP3. In other words, the third electrostatic discharge protective unit ESDP3 is the first switching element **440d**. The third electrostatic discharge protective unit ESDP3 is located in the non-pixel region of the object substrate **400d** and is electrically connected to the N-type bonding pad **451d** through the conductive wire **480d** (such as a side conductive wire), but is not limited thereto.

[0073] FIG. 8 is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. Please referring to FIG. 7 and FIG. 8, an object substrate **400e** is substantially similar to the object substrate **400d** in FIG. 7. The object substrate **400e** is different from the object substrate **400d** mainly in that: a first switching element **440e** (a gate **441e** of the first switching element **440e**) of the object substrate **400d** may be electrically connected to the second thin film transistor **430e** through a conductive wire **481e**, and the first switching element **440e** is electrically connected to the P-type bonding pad **450e** through the second thin film transistor **430e** (such as a source region **434e** of the second thin film transistor **430e**). In the present embodiment, the second thin film transistor **430e** may contact and/or be electrically connected to the conductive wire **481e** through a drain region **433e** of the second thin film transistor **430e**.

[0074] In the present embodiment, a gate **441e** of the first switching element **440e** is electrically connected to a chip **500** and/or the conductive wire **481e**. A first thin film transistor **420e** (such as drain region) is electrically connected to a gate **431e** of the second thin film transistor **430e** through a wire of other cross-section (as shown by the dashed line L4). In the present embodiment, the first switching element **440e** disposed in a non-pixel region of the object substrate **400e** is connected to a ground GND (or low potential, not shown) through the drain region **444e** of the first switching element **440e**, as shown by a dotted line D8. In other words, the P-type bonding pad **450e** can be electrically connected to the ground GND (or low potential, not shown) through the second thin film transistor **430e**, the conductive wire **481e** and the first switching element **440e**. In addition, the N-type bonding pad **451e** is connected to a ground GND through the conductive wire **480e**, as shown by a dotted line D9.

[0075] In the present embodiment, the first switching element **440e** provided or located in the object substrate **400e** can be regarded as a third electrostatic discharge protective unit ESDP3. In other words, the third electrostatic discharge protective unit ESDP3 is the first switching element

440e. The third electrostatic discharge protective unit ESDP3 is located in the non-pixel region of the object substrate **400e**, and the third electrostatic discharge protective unit ESDP3 is electrically connected to the P-type bonding pad **450e** through the conductive wire **480e** (such as a side conductive wire), but is not limited thereto.

[0076] FIG. 9A is a schematic cross-sectional view of an object substrate when transferring a plurality of light emitting units according to another embodiment of the disclosure. FIG. 9B is a schematic circuit diagram of the object substrate in FIG. 9A. Please referring to FIG. 7 and FIG. 9A, an object substrate **400f** in the present embodiment is substantially similar to the object substrate **400d** in FIG. 7. The object substrate **400f** is different from the object substrate **400d** mainly in that: the object substrate **400f** further includes a second switching element **440''**.

[0077] In the present embodiment, a first thin film transistor **420**, a second thin film transistor **430** and the second switching element **440''** are disposed on an upper surface **410a** of a substrate **410**. The second thin film transistor **430** is located or connected between the first thin film transistor **420** and the second switching element **440''**. A first switching element **440f** and a chip **500** are disposed on a bottom surface **410b** of a substrate **410**. The second switching element **440''** and the first switching element **440f** are respectively disposed at two opposite surfaces of the substrate **410** (such as the bottom surface **410b** and the upper surface **410a**).

[0078] A conductive wire **480f** is electrically connected to a N-type bonding pad **451f**, the second switching element **440''** (such as a gate **441''** of the second switching element **440''**), the first switching element **440f** (such as a gate **441f** of the first switching element **440f**) and the chip **500**. The N-type bonding pad **451f** may be electrically connected to a gate **441f** of the first switching element **440f** through the conductive wire **480f**, and the gate **441f** of the first switching element **440f** is electrically connected to a source region **443f** of the first switching element **440f**.

[0079] In the present embodiment, a drain region **444''** of the second switching element **440''** is connected to a source region **443f** of the first switching element **440f**, as shown by a dotted line L5. A drain region **444f** of the first switching element **440f** disposed in a non-pixel region of the object substrate **400f** is connected to a ground GND (or low potential, not shown), as shown by a dotted line D8. In other words, the N-type bonding pad **451f** can be electrically connected to the ground GND (or low potential, not shown) through the conductive wire **480f** and/or the first switching element **440f**, but is not limited thereto.

[0080] In the present embodiment, the first switching element **440f** and the second switching element **440''** provided or located in the object substrate **400f** can be regarded as a third electrostatic discharge protective unit ESDP3. In other words, the third electrostatic discharge protective unit ESDP3 is a combination of the switching elements, such as a combination of the first switching element **440f** and the second switching element **440''**. The number of the switching elements may be adjusted according to demand. The part of the third electrostatic discharge protective unit ESDP3 is located in the pixel region of the object substrate **400f**, and part of the third electrostatic discharge protective unit ESDP3 is located in the non-pixel region of the object substrate **400f**, and the third electrostatic discharge protective unit ESDP3 of the object substrate **400f** is electrically connected to the N-type bonding pad **451f**, but is not limited thereto. In other embodiment, the third electrostatic discharge protective unit ESDP3 is located in the non-pixel region.

[0081] Referring FIG. 9B, in the present embodiment, the object substrate **400f** may include scan lines **470**, data lines **471**, power supply lines **472** (such as VDD), capacitance **473**, signal reference wires **500** (such as VSS), but is not limited thereto.

[0082] In some embodiments (not shown), an ion fan may be used as an electrostatic discharge protective unit. Specifically, positive or negative ions provided by the ion fan are used to neutralize the electrostatic discharge generated during the step of transferring a plurality of light emitting units from a carrier substrate to an object substrate. For example, before picking the plurality of light emitting units from the carrier substrate, the ion fan is turned on to generate positive ions (or

negative ions) to neutralize the electrostatic discharge generated when the grasping heads of the pick-and-place tool contact the plurality of light emitting units, but is not limited thereto. In addition, before placing the plurality of light emitting units onto the object substrate, the ion fan is turned on to generate negative ions (or positive ions) to neutralize the electrostatic discharge generated when the plurality of light emitting units contact to the object substrate, but is not limited thereto.

[0083] It should be noted that, the first electrostatic discharge ESDP1 can represent the electrostatic discharge protective unit located in the pick-and-place tool in the following claims, the second electrostatic discharge ESDP2 can represent the electrostatic discharge protective unit located in the carrier substrate in the following claims, and the third electrostatic discharge ESDP3 can represent the electrostatic discharge protective unit located in the object substrate in the following claims.

[0084] According to the above-mentioned contents, the method for manufacturing an electronic device comprises: transferring a plurality of light emitting units **300** from a carrier substrate (**200** or **200a**) to an object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**) through steps of: picking the plurality of light emitting units **300** from the carrier substrate (**200** or **200a**) by a pick-and-place tool **100**, and placing the plurality of light emitting units **300** onto the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**), wherein the steps are both performed under a protection by at least one electrostatic discharge protective unit (ESDP1, ESDP2 or ESDP3).

[0085] According to the above-mentioned contents, the electronic device comprises at least one first electrostatic discharge protective unit (ESDP1) located in the pick-and-place tool **100** or at least one second electrostatic discharge protective unit (ESDP2) located in the carrier substrate (**200** or **200a**) and/or at least one third electrostatic discharge protective unit (ESDP3) located in the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**).

[0086] The method for manufacturing an electronic device comprise: grounding the at least one first electrostatic discharge protective unit (ESDP1) during the step of transferring the plurality of light emitting units **300** from the carrier substrate (**200** or **200a**) to the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**) when the at least one electrostatic discharge protective unit comprises at least one first electrostatic discharge protective unit (ESDP1).

[0087] The method for manufacturing an electronic device comprise: grounding the at least one second electrostatic discharge protective unit (ESDP2) located in the carrier substrate (**200** or **200a**) and/or the at least one third electrostatic discharge protective unit (ESDP3) located in the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**) during the step of transferring the plurality of light emitting units **300** from the carrier substrate (**200** or **200a**) to the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**) when the at least one electrostatic discharge protective unit comprises at least one second electrostatic discharge protective unit (ESDP2) and/or third electrostatic discharge protective unit (ESDP3).

[0088] According to the above-mentioned contents, the at least one third electrostatic discharge protective unit ESDP3 located in the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**) is electrically connected to the plurality of bonding pads (such as P-type bonding pads or N-type bonding pads of the object substrate). In some embodiments, the at least one third electrostatic discharge protective unit ESDP3 located in the object substrate comprises a plurality of switches (such as the first switching elements and/or second switching elements) for grounding the bonding pads of the object substrate (such as P-type bonding pads or N-type bonding pads) during the step of transferring the plurality of light emitting units **300** from the carrier substrate (**200** or **200a**) to the object substrate (**400**, **400a**, **400c**, **400d**, **400e** or **400f**).

[0089] In summary, in the method of manufacturing the electronic device according to the embodiment of the present disclosure, by providing the at least one electrostatic discharge protective unit in a pick-and-place tool, a carrier substrate and/or an object substrate, the electronic device can be reduced from being damaged by electrostatic discharge during the step of

transferring the plurality of light emitting units from the carrier substrate to the object substrate. Therefore, the method for manufacturing the electronic device according to the embodiments has the effect of increasing the quality or reliability of the electronic device.

[0090] It will be apparent to those skilled in the art that various modifications and variations can be made to the disclosed embodiments without departing from the scope or spirit of the disclosure. In view of the foregoing, it is intended that the disclosure covers modifications and variations provided that they fall within the scope of the following claims and their equivalents.

Claims

1. An electronic device, comprising: a substrate; a first bonding pad disposed on the substrate; a second bonding pad disposed on the substrate; a first electronic unit comprising a first electrode bonding on the first bonding pad; a second electronic unit comprising a second electrode bonding on the second bonding pad; and a conductive wire electrically connecting the first electronic unit and the second electronic unit; wherein a size of the first electronic unit is different from a size of the second electronic unit.
 2. The electronic device according to claim 1, further comprising: a protective unit electrically connected to the first electronic unit.
 3. The electronic device according to claim 2, wherein the protective unit is an electrostatic discharge protective unit.
 4. The electronic device according to claim 1, wherein the first electronic unit and the second electronic unit are respectively disposed on two opposite sides of the substrate.
 5. The electronic device according to claim 4, wherein the substrate comprises a first surface, a second surface opposite to the first surface and a side surface connecting the first surface and the second surface, the first electronic unit is disposed on the first surface, and the second electronic unit is disposed on the second surface.
 6. The electronic device according to claim 5, wherein the conductive wire is disposed on the side surface.
 7. The electronic device according to claim 1, wherein the first bonding pad is electrically connected to a ground or a low potential.
 8. The electronic device according to claim 1, wherein the first electronic unit comprises a diode.
 9. The electronic device according to claim 1, wherein the second electronic unit comprises a chip.
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